Medium power transistor (–60V, –0.5A) **2SA2090**

Features

- 1) High speed switching. (Tf: Typ.: 35ns at Ic = 500mA)
- 2) Low saturation voltage, typically.

(Typ.: -150mV at Ic = -100mA, IB = -10mA)

- Strong discharge power for inductive load and capacitance load.
- 4) Complements the 2SC5868.

Applications

High speed switching, Low noise

TSMT3 (1) Base (2) Emitter (3) Collector (Unit : mm) 1,0 Max. 0,85 0,7 0,85 0,7 0,85 0,7 0,85 0,7 0,85 0,85 0,7 0,85 0,7 0,85

Structure

PNP Silicon epitaxial planar

Packaging Specifications

	Package	Taping	
Type	Code	TL	
	Basic ordering unit (pieces)	3000	
2SA2090		0	

● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit	
Collector-base voltage	Vсво	-60	V	
Collector-emitter voltage	Vceo	-60	V	
Emitter-base voltage	VEBO	-6	V	
Collector current	Ic	-0.5	А	
Collector current	Icp	-1.0	A *1	
Power dissipation	Pc	500	mW *2	
Junction temperature	Tj	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

^{*1} Pw=10ms

^{*2} Each terminal mounted on a recommended land.

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BVceo	-60	_	_	V	Ic= -1mA
Collector-base breakdown voltage	ВУсво	-60	-	_	V	Ic= -100mA
Emitter-base breakdown voltage	ВУєво	-6	_	_	V	I _E = -100μA
Collector cut-off current	Ісво	_	_	-1.0	μΑ	Vcb= -60V
Emitter cut-off current	ІЕВО	_	_	-1.0	μΑ	V _{EB} = -4V
Collector-emitter saturation voltage	VCE(sat)	-	-150	-300	mV	Ic= -100mA, I _B = -10mA
DC current gain	hfe	120	_	270	_	VcE= -2V, Ic= -50mA
Transition frequency	fT	_	400	_	MHz	Vc== -10V, Ie=100mA, f=10MHz *1
Collector output capacitance	Cob	_	10	_	pF	Vcb= -10V, Ie=0mA, f=1MHz
Turn-on time	Ton	_	35	_	ns	Ic= -500mA,
Storage time	Tstg	_	100	_	ns	l _{B1} = -50mA l _{B2} =50mA
Fall time	Tf	_	60	_	ns	Vcc ≃ -25V *1

^{*1} Measured using pulse current

●hfe RANK

Q 120-270

•Electrical characteristic curves

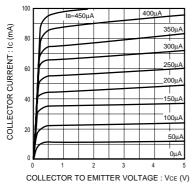


Fig.1 Typical output characteristics

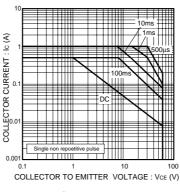


Fig.2 Safe operating area

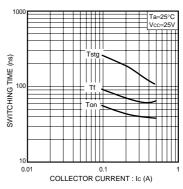


Fig.3 Switching Time

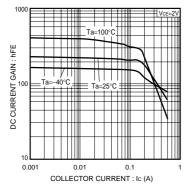


Fig.4 DC current gain vs. collector current (I)

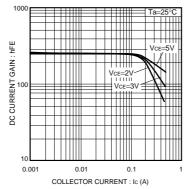


Fig.5 DC current gain vs. collector current (II)

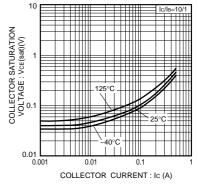


Fig.6 Collector-emitter saturation voltage vs. collector current (I)

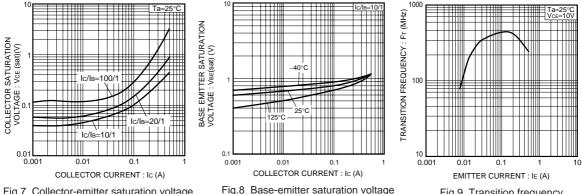


Fig.7 Collector-emitter saturation voltage vs. collector current (II)

Fig.8 Base-emitter saturation voltage vs. collector current

Fig.9 Transition frequency

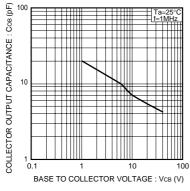


Fig.10 Collector output capacitance

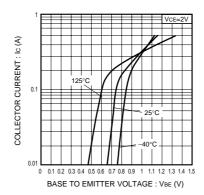
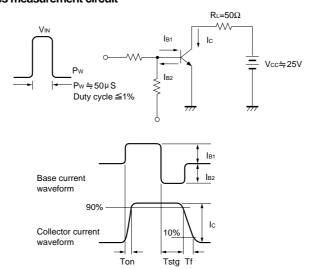


Fig.11 Ground emitter propagation characteristics

Switching characteristics measurement circuit



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